# onsemi

## N-Channel Enhancement Mode Field Effect Transistor FDC653N

V <sub>DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
30 V	0.035 Ω @ 10 V	5.0 A
	0.055 Ω @ 4.5 V	

#### **General Description**

This N-Channel enhancement mode power field effect transistor is produced using **onsemi**'s proprietary, high cell density, DMOS technology. This very high density process is tailored to minimize on-state resistance. These devices are particularly suited for low voltage applications in notebook computers, portable phones, PCMICA cards, and other battery powered circuits where fast switching, and low in-line power loss are needed in a very small outline surface mount package.

#### Features

• 5.0 A, 30 V

$$\begin{split} R_{DS(ON)} &= 0.035 \ \Omega \ @ \ V_{GS} = 10 \ V \\ R_{DS(ON)} &= 0.055 \ \Omega \ @ \ V_{GS} = 4.5 \ V \end{split}$$

- Proprietary SUPERSOT<sup>TM</sup>-6 Package Design Using Copper Lead Frame for Superior Thermal and Electrical Capabilities.
- High Density Cell Design for Extremely Low R<sub>DS(ON)</sub>.
- Exceptional On-Resistance and Maximum DC Current Capability.

ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

• This Device is Pb–Free and Halogen Free

0.055 Ω @ 4.5 V	
D	



#### MARKING DIAGRAM

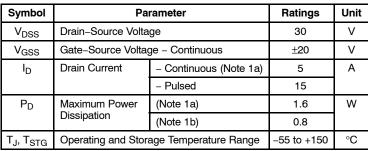


XXX = Specific Device Code

M = Date Code

= Pb–Free Package

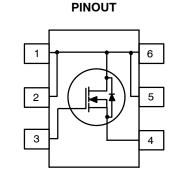
(Note: Microdot may be in either location)



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
Reja	Thermal Resistance, Junction-to-Ambient (Note 1a)	78	°C/W
Rejc	Thermal Resistance, Junction-to-Case (Note 1)	30	°C/W



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

### FDC653N

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
FF CHARA	ACTERISTICS					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}$ = 0 V, I <sub>D</sub> = 250 µA	30	-	-	V
$\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta \text{T}_{\text{J}}}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A,Referenced to $25^{\circ}$ C	-	31	-	mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS}$ = 24 V, $V_{GS}$ = 0 V $T_{J}$ = 55°C			1 10	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS}$ = 20 V, $V_{DS}$ = 0 V	-	-	100	nA
I <sub>GSSR</sub>	Gate-Body Leakage, Reverse	V <sub>GS</sub> = -20 V, V <sub>DS</sub> = 0 V	_	-	-100	nA

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}=V_{GS},I_{D}=250\;\mu A$	1	1.7	2	V
$\frac{\Delta V_{\text{GS(th)}}}{\Delta T_{\text{J}}}$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C	Ι	-4.2	I	mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$V_{GS}$ = 10 V, I <sub>D</sub> = 5 A $T_{J}$ = 125°C $V_{GS}$ = 4.5 V, I <sub>D</sub> = 4.2 A	- -	0.027 0.042 0.046	0.035 0.056 0.055	Ω
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS}$ = 10 V, $V_{DS}$ = 5 V	8	-	-	А
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	-	6.2	-	S

#### DYNAMIC CHARACTERISTICS

C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 15 V, $V_{GS}$ = 0 V, f = 1.0 MHz	-	350	_	pF
C <sub>oss</sub>	Output Capacitance		-	220	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	80	-	pF

#### SWITCHING CHARACTERISTICS (Note 2)

t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ A}, \text{ V}_{GS} = 4.5 \text{ V},$	-	7.5	15	ns
t <sub>r</sub>	Turn–On Rise Time	$R_{GEN} = 6 \Omega$	-	12	25	ns
t <sub>d(off)</sub>	Turn–Off Delay Time		-	13	25	ns
t <sub>f</sub>	Turn–Off Fall Time		-	6	15	ns
Qg	Total Gate Charge	$V_{DS}$ = 15 V, $I_{D}$ = 5 A, $V_{GS}$ = 10 V	-	12	17	nC
Q <sub>gs</sub>	Gate-Source Charge		-	2.1	-	nC
Q <sub>gd</sub>	Gate-Drain Charge		-	2.6	-	nC

#### **DRAIN-SOURCE DIODE CHARACTERISTICS**

I <sub>S</sub>	Continuous Source Diode Current		-	-	1.3	A
$V_{SD}$	Drain-Source Diode Forward Voltage	$V_{GS}$ = 0 V, $I_S$ = 1.3 A (Note 2) $T_J$ = 125°C	-	0.75 0.6	1.2 1.0	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design. a.78°C/W when mounted on a minimum on 1 in<sup>2</sup> pad of 2oz Cu in FR-4 board. b.156°C/W when mounted on a minimum pad of 2oz Cu in FR-4 board.

2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty cycle  $\leq$  2.0 %.

#### FDC653N

#### **TYPICAL CHARACTERISTICS**

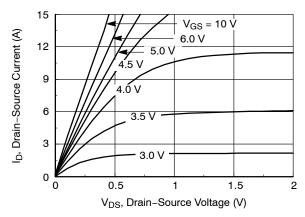
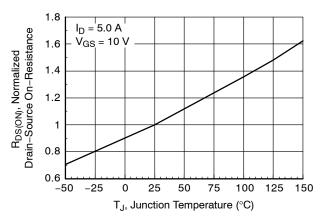


Figure 1. On–Region Characteristics





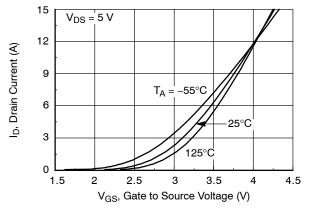


Figure 5. Transfer Characteristics

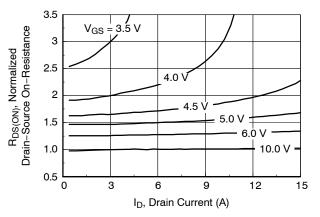


Figure 2. On–Resistance Variation with Drain Current and Gate Voltage

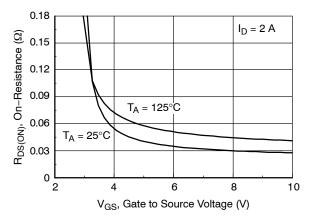


Figure 4. On-Resistance Variation with Gate-to-Source Voltage

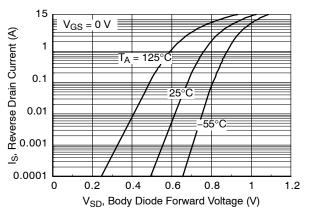


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

#### FDC653N

#### TYPICAL ELECTRICAL CHARACTERISTICS (continued)

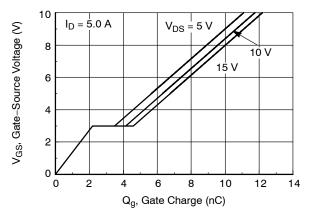


Figure 7. Gate Charge Characteristics

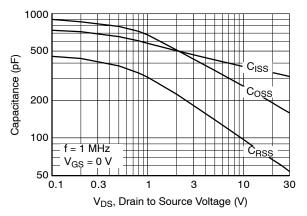


Figure 8. Capacitance Characteristics

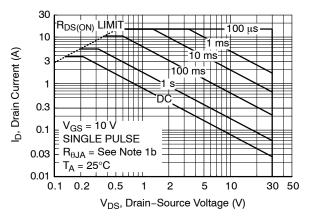


Figure 9. Maximum Safe Operating Area

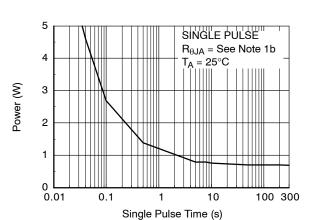
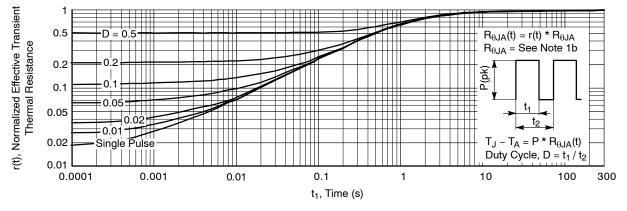


Figure 10. Single Pulse Maximum Power Dissipation



**Figure 11. Transient Thermal Response Curve** (Note: Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.)

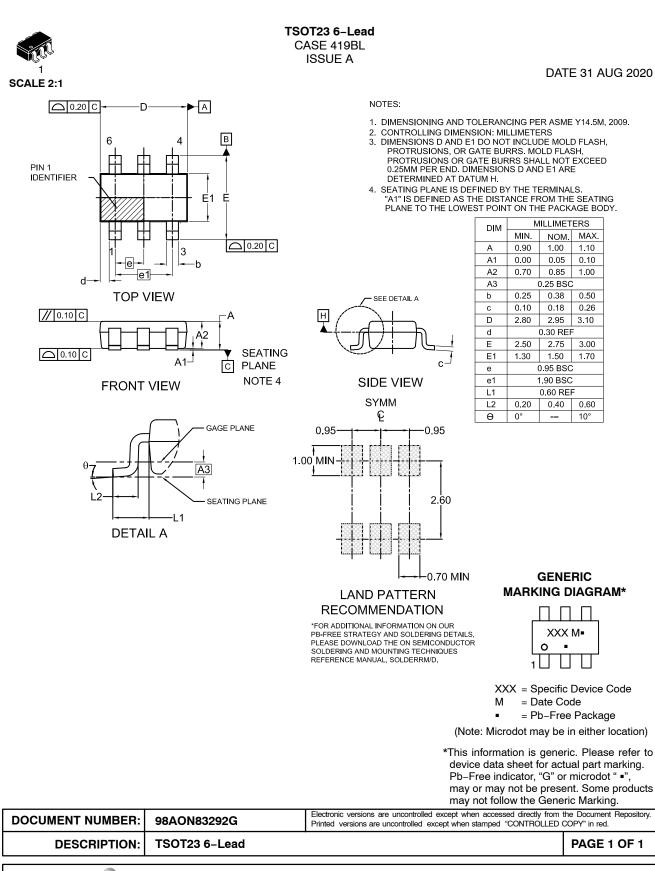
#### **ORDERING INFORMATION**

Device	Device Marking	Package Type	Reel Size	Tape Width	Shipping <sup>†</sup>
FDC653N	.653	TSOT23 6-Lead (Pb-free)	7"	8 mm	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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